

Vishay Semiconductors

ROHS

HALOGEN

FREE

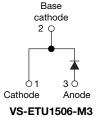
Ultrafast Rectifier, 15 A FRED Pt®



2L TO-220AC



2L TO-220 FULL-PAK





VS-ETU1506FP-M3

PRODUCT SUMMARY	
Package	2L TO-220AC, 2L TO-220FP
I _{F(AV)}	15 A
V_{R}	600 V
V _F at I _F	1.1 V
t _{rr} (typ.)	24 ns
T _J max.	175 °C
Diode variation	Single die

FEATURES

- Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

State of the art, ultralow V_F , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current in DC	I _{F(AV)}	T _C = 151 °C	15	А		
Average rectified forward current in DC FULL-PAK		T _C = 103 °C	15			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	160			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	YMBOL TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R			-	-	.,	
Forward voltage	V _F	I _F = 15 A	-	1.35	1.9	V	
Forward voltage		I _F = 15 A, T _J = 150 °C	-	1.1	1.3		
Devenue leekage euggest		$V_R = V_R$ rated	-	0.01	15		
Reverse leakage current I _R		T _J = 150 °C, V _R = V _R rated	-	20	200	μA	
Junction capacitance	C _T	V _R = 600 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	



VS-ETU1506-M3,VS-ETU1506FP-M3

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100$	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		24	28	
Reverse recovery time		$I_F = 15 \text{ A}, dI_F/dt = 10$	$I_F = 15 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		36	47	
neverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	ns
		T _J = 125 °C	$I_F = 15 \text{ A}$ $dI_F/dt = 200 \text{ A/µs}$ $V_R = 390 \text{ V}$	-	87	-	
Peak recovery current	1	T _J = 25 °C		-	5	-	A nC
reak recovery current	I _{RRM}	T _J = 125 °C		-	9	-	
Devene vecesient eberge		T _J = 25 °C		-	107	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	430	-	
Reverse recovery time	t _{rr}	T _J = 125 °C	$I_F = 15 \text{ A}$ $dI_F/dt = 800 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	53	-	ns
Peak recovery current	I _{RRM}			-	25	-	Α
Reverse recovery charge	Q _{rr}			-	730	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance,	D		ı	1.2	1.4	
junction to case FULL-PAK	R_{thJC}		-	3.7	4.3	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
\\/-:- -t			-	2	-	g
Weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking daying		Case style 2L TO-220AC	e style 2L TO-220AC ET		1506	
Marking device		Case style 2L TO-220 FULL-PAK		ETU1	506FP	



Vishay Semiconductors

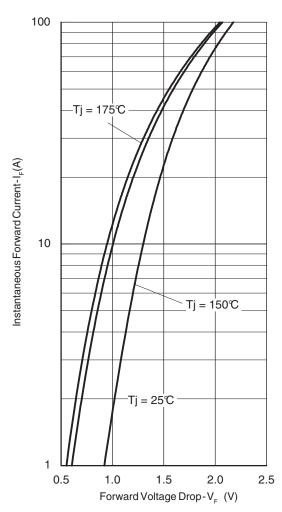


Fig. 1 - Typical Forward Voltage Drop Characteristics

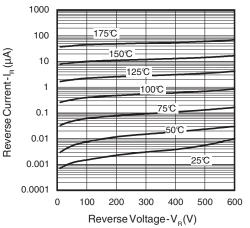


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

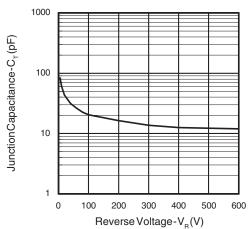


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

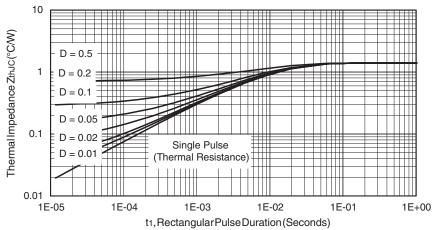


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

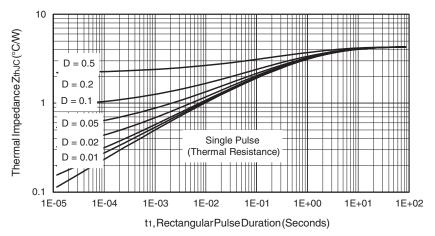


Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FULL-PAK)

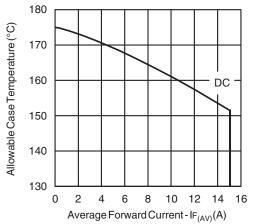


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

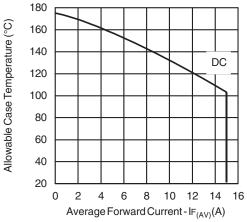


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

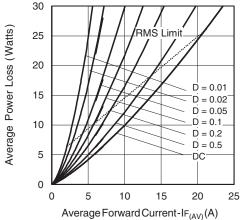


Fig. 8 - Forward Power Loss Characteristics

Vishay Semiconductors

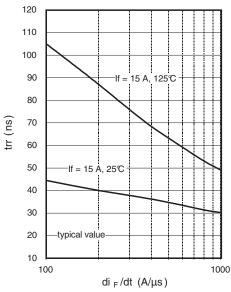


Fig. 9 - Typical Reverse Recovery vs. dl_F/dt

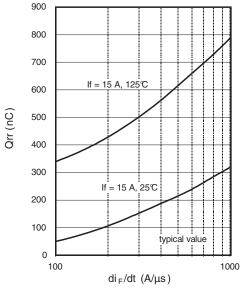


Fig. 10 - Typical Stored Charge vs. dl_F/dt

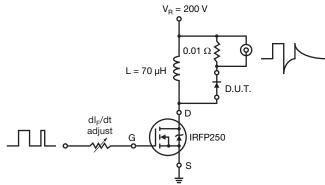
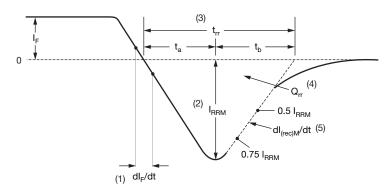


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

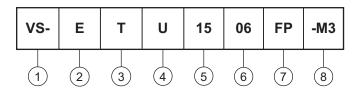
Fig. 12 - Reverse Recovery Waveform and Definitions

VS-ETU1506-M3,VS-ETU1506FP-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode

3 - T = TO-220

4 - U = hyperfast recovery time

Current code: 15 = 15 A

Voltage code: 06 = 600 V

7 - • None = TO-220

• FP = FULL-PAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-ETU1506-M3	50	1000	Antistatic plastic tube		
VS-ETU1506FP-M3	50	1000	Antistatic plastic tube		

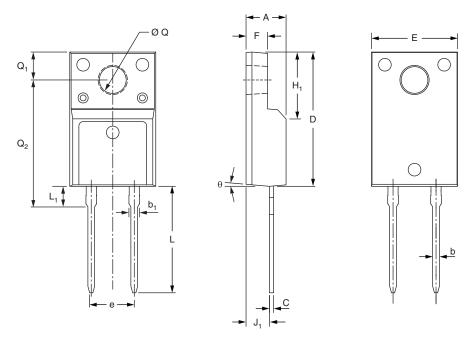
LINKS TO RELATED DOCUMENTS				
Dimensions	2L TO-220AC	www.vishay.com/doc?95259		
Dimensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260		
Part marking information	2L TO-220AC	www.vishay.com/doc?95391		
	2L TO-220 FULL-PAK	www.vishay.com/doc?95392		



Vishay Semiconductors

True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches



CYMPOL	MILLIN	MILLIMETERS		IES
SYMBOL	MIN.	MAX.	MIN.	MAX.
Α	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08 t	ypical	0.200 typical	
F	2.34	2.74	0.092	0.107
H ₁	6.50	6.90	0.256	0.272
J ₁	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L ₁	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q ₁	3.10	3.50	0.122	0.138
Q ₂	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.